



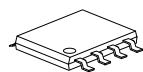
# U74AHC2G32

CMOS IC

## DUAL 2-INPUT OR GATE

### ■ DESCRIPTION

The **U74AHC2G32** is a high speed Si-gate CMOS device.  
The **U74AHC2G32** provides two 2-input OR gates.



TSSOP-8

### ■ FEATURES

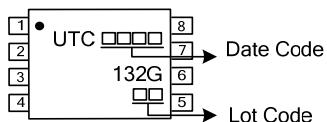
- \* Symmetrical output impedance
- \* High noise immunity
- \* Low power dissipation
- \* Balanced propagation delays
- \* Multiple package options
- \* Specified from -40 °C to +125 °C

### ■ ORDERING INFORMATION

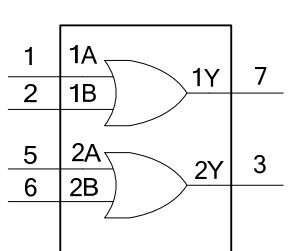
Ordering Number	Package	Packing
U74AHC2G32G-P08-R	TSSOP-8	Tape Reel

U74AHC2G32G-P08-R	<ul style="list-style-type: none"><li>(1)Packing Type</li><li>(2)Package Type</li><li>(3)Green Package</li></ul>	<ul style="list-style-type: none"><li>(1) R: Tape Reel</li><li>(2) P08: TSSOP-8</li><li>(3) G: Halogen Free and Lead Free</li></ul>
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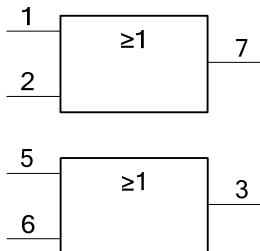
### ■ MARKING



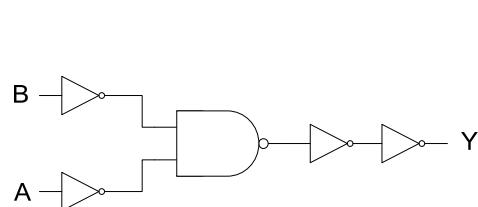
## ■ FUNCTIONAL DIAGRAM



LOGIC SYMBOL

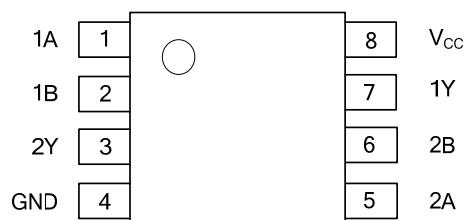


IEC LOGIC SYMBOL



LOGIC DIAGRAM (one gate)

## ■ PIN CONFIGURATION



## ■ PIN CONFIGURATION

PIN No	SYMBOL	DESCRIPTION
1, 5	1A, 2A	Data input
2, 6	1B, 2B	Data input
4	GND	Ground (0V)
7, 3	1Y, 2Y	Data output
8	V <sub>CC</sub>	Supply voltage

## ■ FUNCTION TABLE

Input		Output
nA	nB	nY
L	L	L
L	H	H
H	L	H
H	H	H

H=HIGH voltage level; L=LOW voltage level.

### ■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V <sub>CC</sub>		-0.5		+7.0	V
Input Voltage	V <sub>I</sub>		-0.5		+7.0	V
Input Clamping Current	I <sub>IK</sub>	V <sub>I</sub> <-0.5V	-20			mA
Output Clamping Current	I <sub>OK</sub>	V <sub>O</sub> <-0.5V or V <sub>O</sub> >V <sub>CC</sub> +0.5V			±20	mA
Output Current	I <sub>O</sub>	V <sub>O</sub> =-0.5V ~ (V <sub>CC</sub> +0.5V)			±25	mA
Supply Current	I <sub>CC</sub>				75	mA
Ground Current	I <sub>GND</sub>		-75			mA
Power Dissipation	P <sub>D</sub>				250	mW
Storage Temperature	T <sub>STG</sub>		-65		+150	°C

Note: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### ■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V <sub>CC</sub>		2	5	5.5	V
Input Voltage	V <sub>I</sub>		0		5.5	V
Output Voltage	V <sub>O</sub>		0		V <sub>CC</sub>	V
Input Transition Rise and Fall Rate	Δt/ΔV	V <sub>CC</sub> =3.3V±0.3V			100	ns/V
		V <sub>CC</sub> =5V±0.5V			20	
Ambient Temperature	T <sub>A</sub>		-40	+25	+125	°C

Note: Voltages are referenced to GND (ground=0V).

### ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub> =25°C , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
High-level Input Voltage	V <sub>IH</sub>	V <sub>CC</sub> =2V	1.5			V
		V <sub>CC</sub> =3V	2.1			
		V <sub>CC</sub> =5.5V	3.85			
Low-level Input Voltage	V <sub>IL</sub>	V <sub>CC</sub> =2V			0.5	V
		V <sub>CC</sub> =3V			0.9	
		V <sub>CC</sub> =5.5V			1.65	
Output Voltage HIGH-Level	V <sub>OH</sub>	V <sub>CC</sub> =2V, I <sub>OH</sub> =-50μA	1.9	2.0		V
		V <sub>CC</sub> =3V, I <sub>OH</sub> =-50μA	2.9	3.0		
		V <sub>CC</sub> =4.5V, I <sub>OH</sub> =-50μA	4.4	4.5		
		V <sub>CC</sub> =3V, I <sub>OH</sub> =-4mA	2.58			
		V <sub>CC</sub> =4.5V, I <sub>OH</sub> =-8mA	3.94			
Output Voltage LOW-Level	V <sub>OL</sub>	V <sub>CC</sub> =2V, I <sub>OL</sub> =50μA		0	0.1	V
		V <sub>CC</sub> =3V, I <sub>OL</sub> =50μA		0	0.1	
		V <sub>CC</sub> =4.5V, I <sub>OL</sub> =50μA		0	0.1	
		V <sub>CC</sub> =3V, I <sub>OL</sub> =4mA			0.36	
		V <sub>CC</sub> =4.5V, I <sub>OL</sub> =8mA			0.36	
Input Leakage Current	I <sub>I</sub>	V <sub>CC</sub> =0 to 5.5V, V <sub>I</sub> = 5.5V or GND			±0.1	μA
Quiescent Supply Current	I <sub>CC</sub>	V <sub>CC</sub> =5.5V, V <sub>I</sub> =V <sub>CC</sub> or GND, I <sub>OUT</sub> =0			1	μA

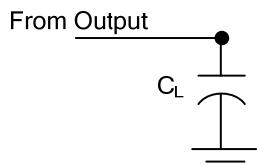
■ SWITCHING CHARACTERISTICS ( $t_r = t_f \leq 3\text{ns}$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Propagation delay from input (nA, nB) to output (nY)	$t_{PLH} / t_{PHL}$	$V_{CC}=3\sim 3.6V$	$C_L=15\text{pF}$		4.4	7.9	ns
			$C_L=50\text{pF}$		6.3	11.4	ns
	$t_{PLH} / t_{PHL}$	$V_{CC}=4.5\sim 5.5V$	$C_L=15\text{pF}$		3.2	5.5	ns
			$C_L=50\text{pF}$		4.6	7.5	ns

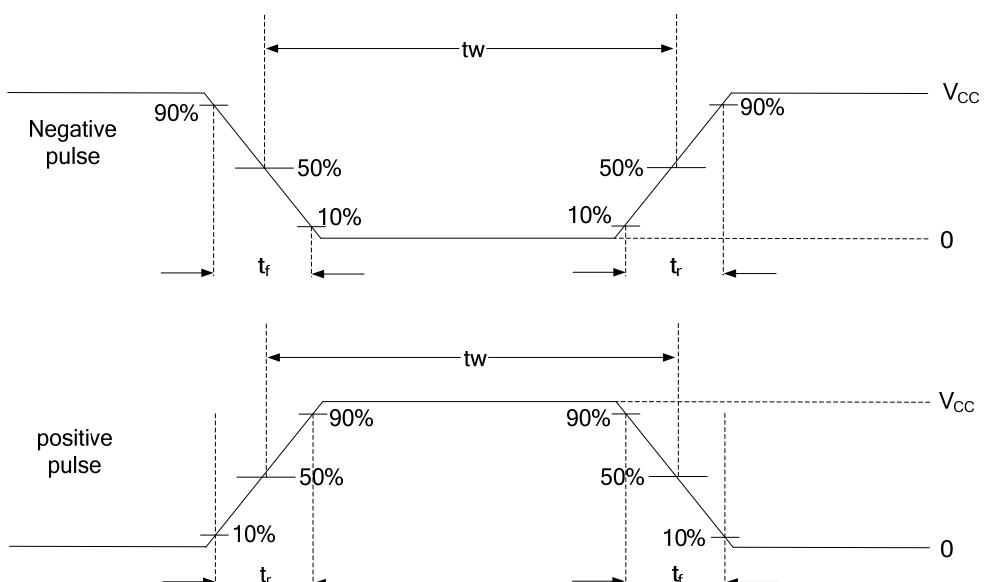
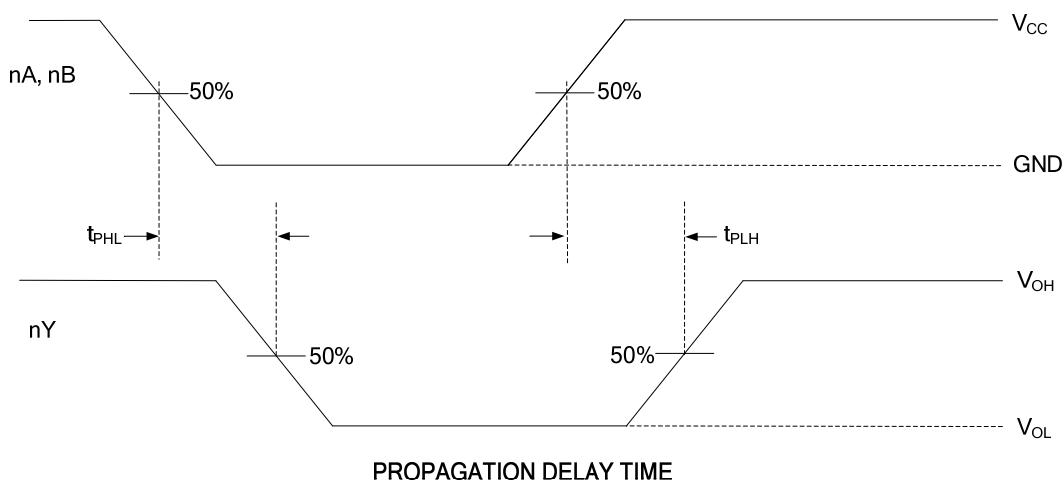
■ CAPACITIVE CHARACTERISTICS ( $T_A=25^\circ\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Capacitance	$C_I$			1.5	10	pF
Power Dissipation Capacitance	$C_{PD}$	per buffer; $C_L=50\text{pF}$ ; $f_i=1\text{MHz}$ ; $V_i=\text{GND}$ to $V_{CC}$		16		pF

■ TEST CIRCUIT AND WAVEFORMS



TEST CIRCUIT



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